

## Supplementary Information for

# Pressure-Driven Responses in $\text{Cd}_2\text{SiO}_4$ and $\text{Hg}_2\text{GeO}_4$ Minerals: A Comparative Study

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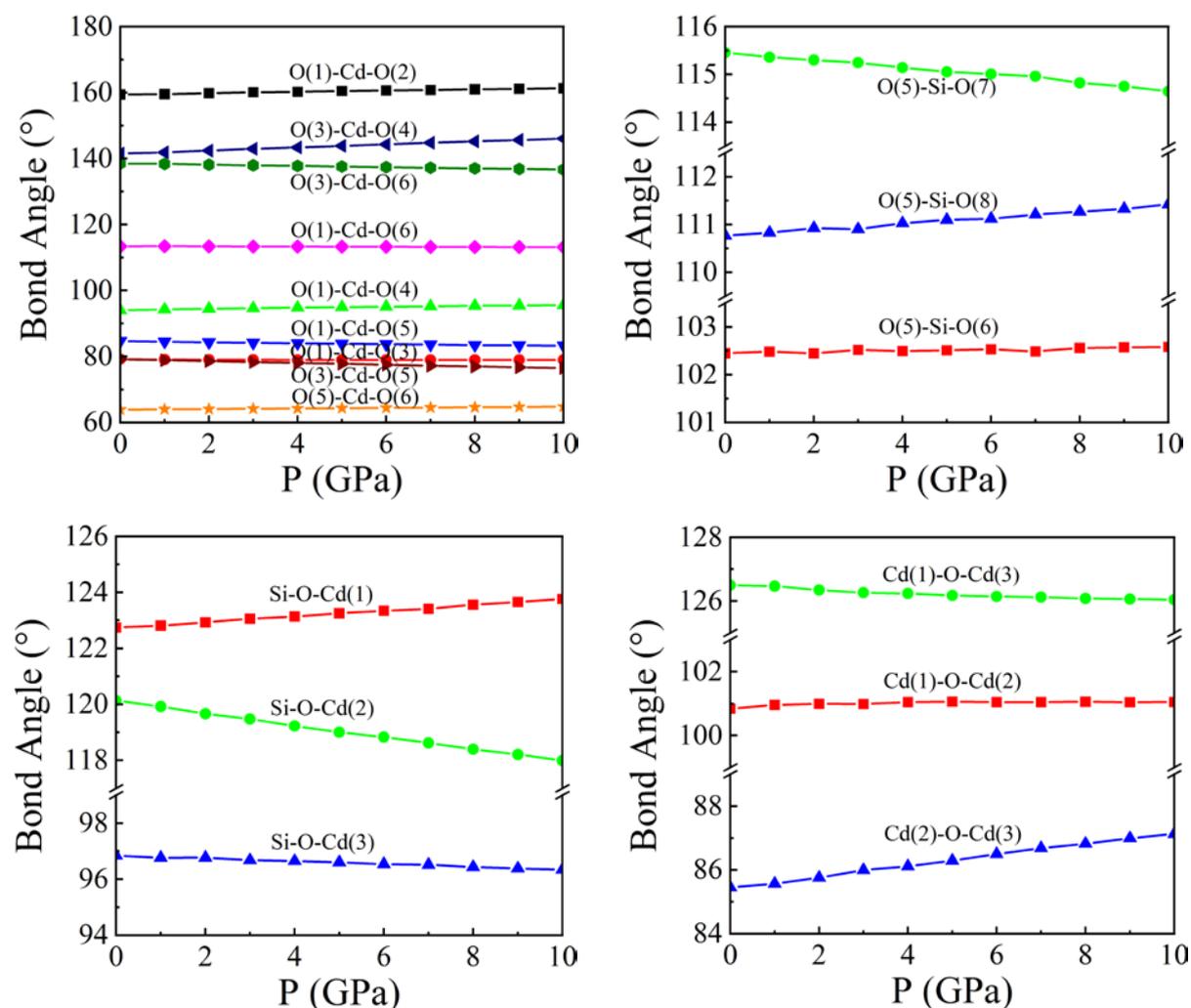


Figure S1. The pressure dependence of selected bond angles of  $\text{Cd}_2\text{SiO}_4$

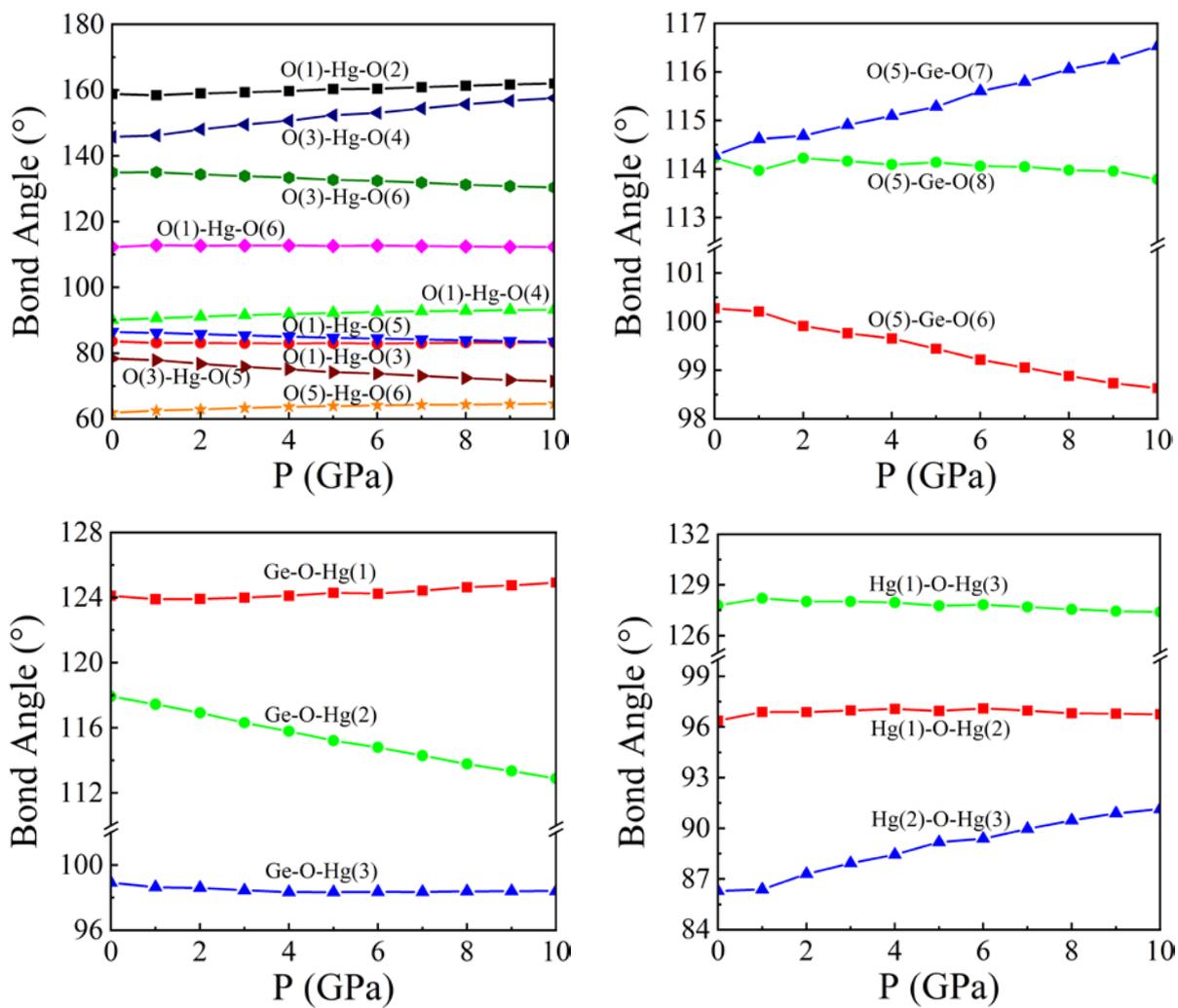


Figure S2. The pressure dependence of selected bond angles of  $\text{Hg}_2\text{GeO}_4$